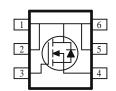
N-Channel 20V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

PRODUCT SUMMARY				
$V_{DS}(V)$	$r_{DS(on)}(OHM)$	$I_D(A)$		
30	0.032 @ V _{CS} =4.5 V	6.0		
	0.044 @ V _{CS} =2.5V	5.0		

- Low r_{DS(on)} provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe TSOP-6 saves board space
- · Fast switching speed
- High performance trench technology





ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)							
Parameter			Maximum	Units			
Drain-Source Voltage			30	V			
Gate-Source Voltage			±12	v			
Continuous Drain Current ^a	$T_A=25^{\circ}C$. т_	6.0				
Continuous Drain Current	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	ъ	4.6	A			
Pulsed Drain Current ^b		I_{DM}	±20				
Continuous Source Current (Diode Conduction) ^a		I_S	1.6	A			
D a	$T_A=25^{\circ}C$	D	2.0				
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	I D	1.3	W			
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C			

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Maximum	Units			
M · I · · · a	t <= 5 sec	D	62.5	0C/W		
Maximum Junction-to-Ambient ^a	Steady-State	$\mathbf{K}_{\mathrm{THJA}}$	110	°C/W		

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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D .			Limits				
Parameter	Symbol	Symbol Test Conditions		Тур	Max	Unit	
Static							
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$	0.7		1.5	V	
Gate-Body Leakage	I_{GSS}	$V_{DS}=0$ V, $V_{GS}=\pm 8$ V			±100	nA	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
Ç	-D88	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			10	uz i	
On-State Drain Current ^A	$I_{D(on)}$	$V_{DS} = 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	10			A	
Drain-Source On-Resistance ^A		$V_{GS} = 4.5 \text{ V}, I_D = 6.0 \text{ A}$			32	mOHM	
Diani-Source On-Resistance	r _{DS(on)}	$V_{GS} = 2.5 \text{ V}, I_D = 5.0 \text{ A}$			44	шонм	
Forward Tranconductance ^A	g_{fs}	$V_{DS} = 10 \text{ V}, I_D = 4.0 \text{ A}$		11.3		S	
Diode Forward Voltage	V_{SD}	$I_S = 1.6 \text{ A}, V_{GS} = 0 \text{ V}$		0.75		V	
Dynamic ^b							
Total Gate Charge	$Q_{\rm g}$			6.0			
Gate-Source Charge	Q_{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 4.0 \text{ A}$		1.0		nC	
Gate-Drain Charge	Q_{gd}			1.5			
Turn-On Delay Time	t _{d(on)}			8			
Rise Time	t _r	$V_{DD} = 10 \text{ V}, R_L = 15 \text{ O}, I_D = 1 \text{ A},$		24			
Turn-Off Delay Time	t _{d(off)}	$V_{GEN} = 4.5 \text{ V}$		35		ns	
Fall-Time	t _f			10			

Notes

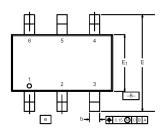
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

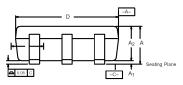
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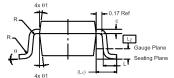
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Package Information

TSOP-6: 6LEAD







	MILLIMETERS			ı	INCHES	•
Dim	Min	Nom	Max	Min	Nom	Max
Α	0.91	-	1.10	0.036	-	0.043
A ₁	0.01	-	0.10	0.0004	-	0.004
A ₂	0.84	_	1.00	0.033	0.038	0.039
b	0.30	0.32	0.45	0.012	0.013	0.018
С	0.10	0.15	0.20	0.004	0.006	0.008
D	2.95	3.05	3.10	0.116	0.120	0.122
E	2.70	2.85	2.98	0.106	0.112	0.117
E ₁	1.55	1.65	1.70	0.061	0.065	0.067
е	1.00 BSC			0.0394 BSC		
L	0.35	-	0.50	0.014 - 0.02		
L ₁	0.60 Ref			0.024 Ref		
L ₂	0.25 BSC			0.010 BSC		
R	0.10	_	_	0.004	-	_
θ	0°	4°	8°	0°	4°	8°
θ_1	7° Nom			7° Nom		

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